National Semiconductor

July 1998

DS36950
Quad Differential Bus Transceiver

General Description

The DS36950 is a low power, space-saving quad EIA-485 differential bus transceiver especially suited for high speed, parallel, multipoint, computer I/O bus applications. A compact 20-pin surface mount PLCC package provides high transceiver integration and a very small PC board footprint.

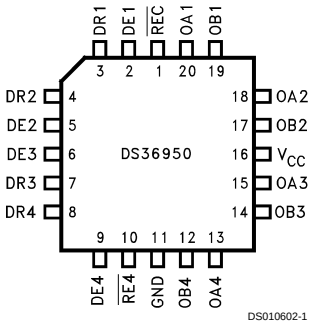
Timing uncertainty across an interface using multiple devices, a typical problem in a parallel interface, is specified — minimum and maximum propagation delay times are guaranteed.

Six devices can implement a complete IPI master or slave interface. Three transceivers in a package are pinned out for connection to a parallel databus. The fourth transceiver, with the flexibility provided by its individual enables, can serve as a control bus transceiver.

Features

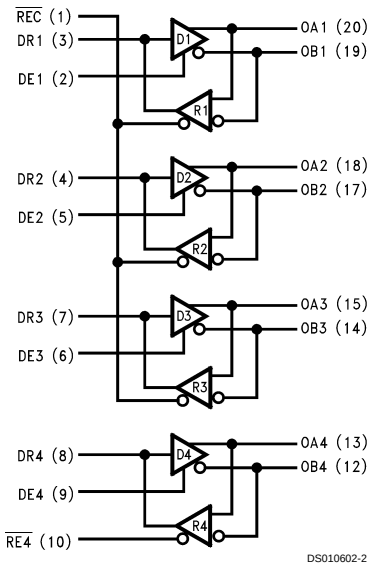
- Pinout for IPI interface
- Compact 20-pin PLCC package
- Meets EIA-485 standard for multipoint bus transmission
- Greater than 60 mA source/sink
- Thermal Shutdown Protection

Pinout and Logic Diagram



DS010602-1

Order Number DS36950
See NS Package Number V20A



DS010602-2

TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	7V
Control Input Voltage	V_{CC} + 0.5V
Driver Input Voltage	V_{CC} + 0.5V
Driver Output Voltage/Receiver Input Voltage	−10V to +15V
Receiver Output Voltage	5.5V
Continuous Power Dissipation @ 25˚C V Package	1.73W
Derate V Package 13.9 mW/˚C above 25˚C	
Storage Temp. Range	−65˚C to +150˚C
Lead Temp. (Soldering 4 Sec.)	260˚C

Recommended Operating Conditions

Supply Voltage, V_{CC}	4.75V to 5.25V
Bus Voltage	−7V to +12V
Operating Free Air Temp. (T_A)	0˚C to +70˚C

Electrical Characteristics (Note 2)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DRIVER CHARACTERISTICS						
V_{ODL}	Differential Driver Output Voltage (Full Load)	I_L = 60 mA, V_{CM} = 0V	1.5	1.9		V
V_{OD}	Differential Driver Output Voltage (Termination Load)	R_L = 100Ω (EIA-422)	2.0	3.5		V
		R_L = 54Ω (EIA-485)	1.5	3.2		V
$\Delta\lvert V_{OD}\rvert$	Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	R_L = 54Ω or 100Ω (Note 4) (*Figure 1*) (EIA-485)			0.2	V
V_{OC}	Driver Common Mode Output Voltage (Note 5)	R_L = 54Ω (*Figure 1*) (EIA-485)			3.0	V
$\Delta\lvert V_{OC}\rvert$	Change in Magnitude of Common Mode Output Voltage	(Note 4) (*Figure 1*) (EIA-485)			0.2	V
V_{OH}	Output Voltage HIGH	I_{OH} = −55 mA	2.7	3.2		V
V_{OL}	Output Voltage LOW	I_{OL} = 55 mA		1.4	1.7	V
V_{IH}	Input Voltage HIGH		2.0			V
V_{IL}	Input Voltage LOW				0.8	V
V_{CL}	Input Clamp Voltage	I = −18 mA			−1.5	V
I_{IH}	Input High Current	V_I = 2.4V (Note 3)			20	µA
I_{IL}	Input Low Current	V_I = 0.4V (Note 3)			−20	µA
I_{OSC}	Driver Short-Circuit Output Current (Note 9)	V_O = −7V (EIA-485)		−130	−250	mA
		V_O = 0V (EIA-422)		−90	−150	mA
		V_O = +12V (EIA-485)		130	250	mA
RECEIVER CHARACTERISTICS						
I_{OSR}	Short Circuit Output Current	V_O = 0V (Note 9)	−15	−28	−75	mA
I_{OZ}	TRI-STATE® Output Current	V_O = 0.4V to 2.4V			20	µA
V_{OH}	Output Voltage High	V_{ID} = 0.20V, I_{OH} = −0.4 mA	2.4	3.0		V
V_{OL}	Output Voltage Low	V_{ID} = −0.20V, I_{OL} = 4 mA		0.35	0.5	V
V_{TH}	Differential Input High Threshold Voltage	V_O = V_{OH}, I_O = −0.4 mA (EIA-422/485)		0.03	0.20	V
V_{TL}	Differential Input Low Threshold Voltage (Note 6)	V_O = V_{OL}, I_O = 4.0 mA (EIA-422/485)	−0.20	−0.03		V
V_{HST}	Hysteresis (Note 7)	V_{CM} = 0V	35	60		mV
DRIVER AND RECEIVER CHARACTERISTICS						
V_{IH}	Enable Input Voltage High		2.0			V
V_{IL}	Enable Input Voltage Low				0.8	V
V_{CL}	Enable Input Clamp Voltage	I = −18 mA			−1.5	V
I_{IN}	Line Input Current	Other Input = 0V, V_I = +12V		0.5	1	mA

Electrical Characteristics (Note 2) (Continued)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Parameter	Conditions		Min	Typ	Max	Units
DRIVER AND RECEIVER CHARACTERISTICS							
	(Note 8)		V_I = −7V		−0.45	−0.8	mA
I_{IH}	Enable Input Current High	V_{OH} = 2.4V	$\overline{RE4}$ or DE			20	µA
			$\overline{REC}$			60	µA
I_{IL}	Enable Input Current Low	V_{OL} = 0.4V	$\overline{RE4}$ or DE			−20	µA
			$\overline{REC}$			−60	µA
I_{CC}	Supply Current (Note 10)	No Load, Outputs Enabled			75	90	mA
I_{CCZ}	Supply Current (Note 10)	No Load, Outputs Disabled			50	70	mA

Switching Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Conditions		Min	Typ	Max	Units
DRIVER SINGLE-ENDED CHARACTERISTICS						
t_{PZH}	R_L = 110Ω (*Figure 4*)			35	40	ns
t_{PZL}	R_L = 110Ω (*Figure 5*)			25	40	ns
t_{PHZ}	R_L = 110Ω (*Figure 4*)			15	25	ns
t_{PLZ}	R_L = 110Ω (*Figure 5*)			35	40	ns
DRIVER DIFFERENTIAL CHARACTERISTICS						
t_R, t_F	Rise & Fall Time	R_L = 54Ω		13	16	ns
t_{PLHD}	Differential Propagation	C_L = 50 pF	9	15	19	ns
t_{PHLD}	Delays (Note 15)	C_D = 15 pF	9	15	19	ns
t_{SKD}	$\lvert t_{PLHD} - t_{PHLD} \rvert$ Differential Skew	(*Figures 3, 8*)		3	6	ns
RECEIVER CHARACTERISTICS						
t_{PLHD}	Differential Propagation Delays		9	14	19	ns
t_{PHLD}	C_L = 15 pF, V_{CM} = 1.5V (*Figure 6*)		9	14	19	ns
t_{SKD}	$\lvert t_{PLHD} - t_{PHLD} \rvert$ Differential Receiver Skew			1	3	ns
t_{ZH}	Output Enable Time to High Level			15	22	ns
t_{ZL}	Output Enable Time to Low Level	C_L = 15 pF		20	30	ns
t_{HZ}	Output Disable Time from High Level	(*Figure 7*)		10	17	ns
t_{LZ}	Output Disable Time from Low Level			17	25	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Current into device pins is define as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.

Note 3: I_{IH} and I_{IL} includes driver input current and receiver TRI-STATE leakage current.

Note 4: $\Delta|V_{OD}|$ and $\Delta|V_{OC}|$ are changes in magnitude of V_{OD} and V_{OC}, respectively, that occur when the input changes state.

Note 5: In EIA Standards EIA-422 and EIA-485, V_{OC}, which is the average of the two output voltages with respect to ground, is called output offset voltage, V_{OS}.

Note 6: Threshold parameter limits specified as an algebraic value rather than by magnitude.

Note 7: Hysteresis defined as $V_{HST} = V_{TH} - V_{TL}$.

Note 8: I_{IN} includes the receiver input current and driver TRI-STATE leakage current.

Note 9: Short one output at a time.

Note 10: Total package supply current.

Note 11: All typicals are given for V_{CC} = 5.0V and T_A = 25˚C.

Parameter Measurement Information

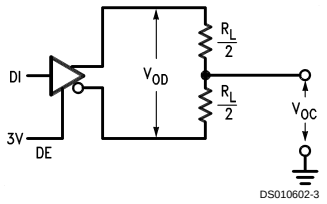


FIGURE 1. Driver V_{OD} and V_{OC}

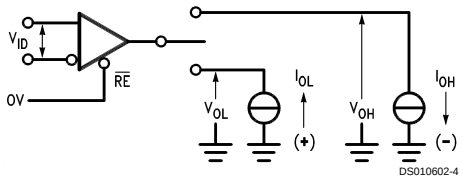
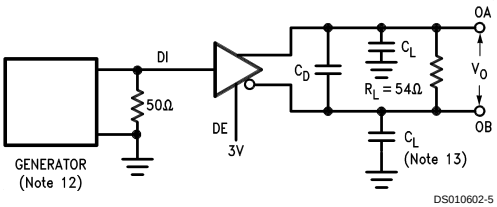


FIGURE 2. Receiver V_{OH} and V_{OL}



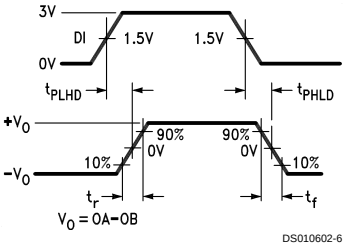
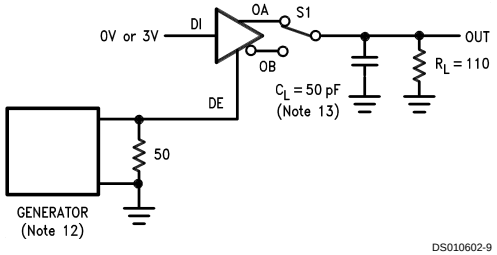


FIGURE 3. Driver Differential Propagation Delay and Transition Timing



S1 to OA for DI = 3V
S1 to OB for DI = 0V

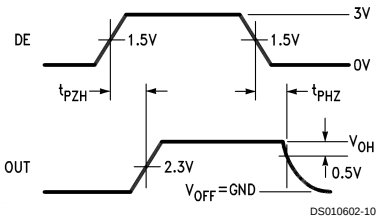
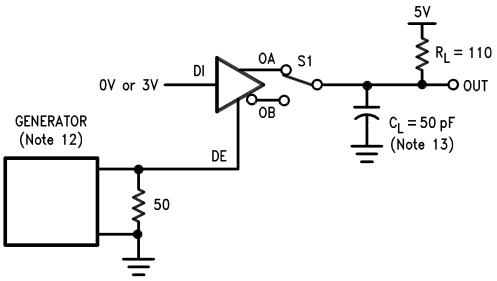


FIGURE 4. Driver Enable and Disable Timing (t_{PZH}, t_{PHZ})



S1 to OA for DI = 0V
S1 to OB for DI = 3V

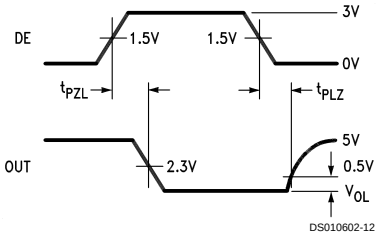
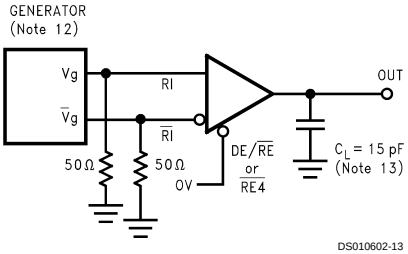


FIGURE 5. Driver Enable and Disable Timing (t_{PZL}, t_{PLZ})

Parameter Measurement Information (Continued)



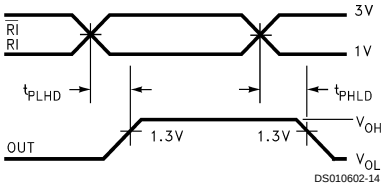
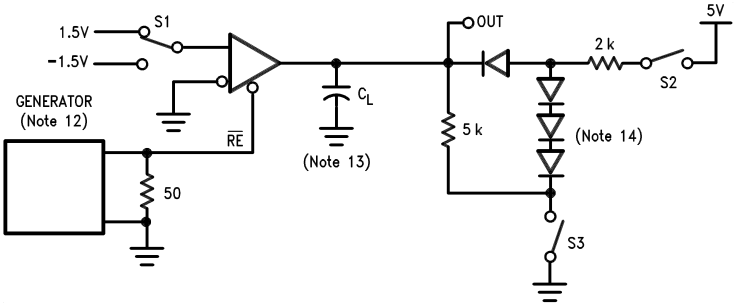
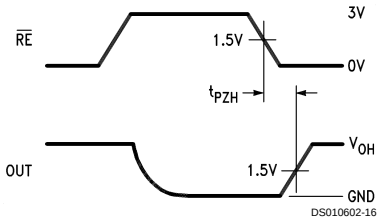
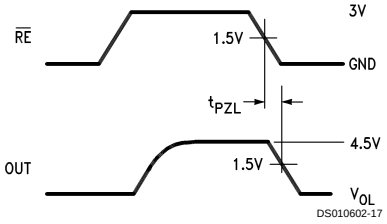


FIGURE 6. Receiver Differential Propagation Delay Timing

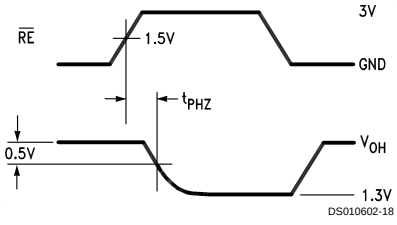




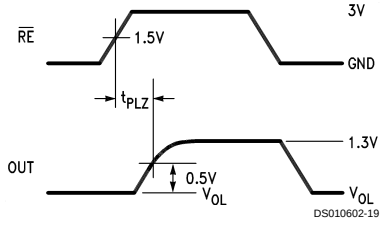
S1 1.5V
S2 OPEN
S3 CLOSED



S1 −1.5V
S2 CLOSED
S3 OPEN



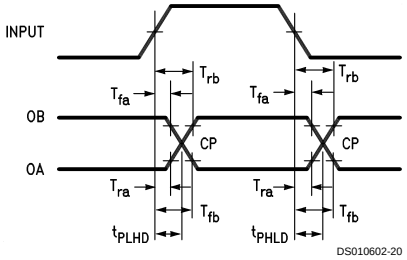
S1 1.5V
S2 CLOSED
S3 CLOSED



S1 −1.5V
S2 CLOSED
S3 CLOSED

FIGURE 7. Receiver Enable and Disable Timing

Parameter Measurement Information (Continued)



TCP = Crossing Point
Tra, Trb, Tfa, and Tfb are propagation delay measurements to the 20% and 80% levels.

$$TCP = \frac{(Tfb \times Trb) - (Tra \times Tfa)}{Trb - Tra - Tfa + Tfb}$$

FIGURE 8. Propagation Delay Timing for Calculation of Driver Differential Propagation Delays

Note 12: The input pulse is supplied by a generator having the following characteristics:
f = 1.0 MHz, 50% Duty Cycle, t_f and t_r < 6.0 ns, Z_O = 50Ω

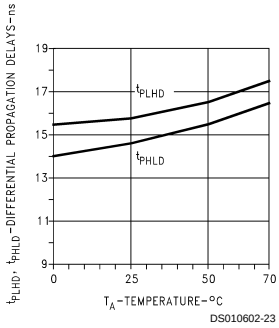
Note 13: C_L includes probe and stray capacitance.

Note 14: Diodes are 1N916 or equivalent.

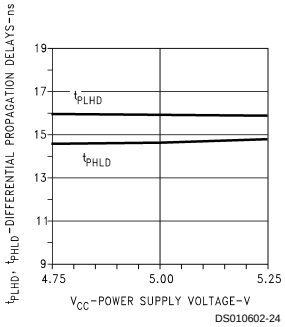
Note 15: Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver outputs (See *Figure 8*).

Typical Performance Characteristics

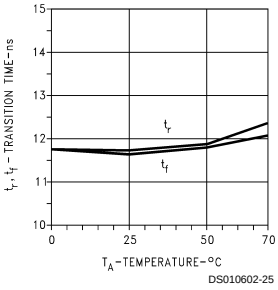
Driver Differential Propagation Delay vs Temperature



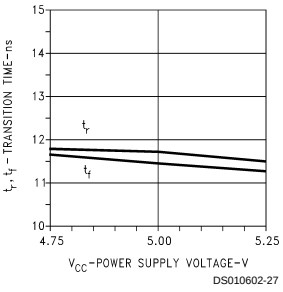
Driver Differential Propagation Delay vs V_{CC}



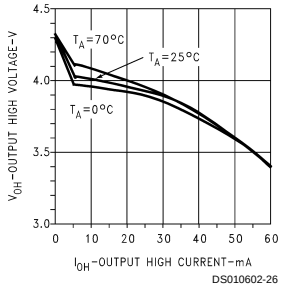
Driver Transition Time vs Temperature



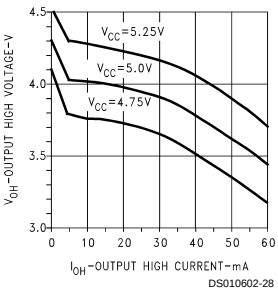
Driver Transition Time vs V_{CC}



Driver V_{OH} vs I_{OH} vs Temperature

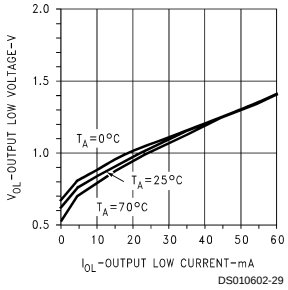


Driver V_{OH} vs I_{OH} vs V_{CC}

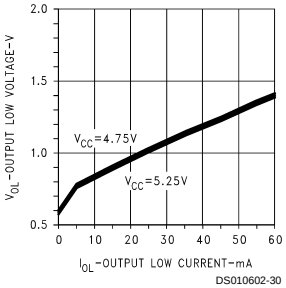


Typical Performance Characteristics (Continued)

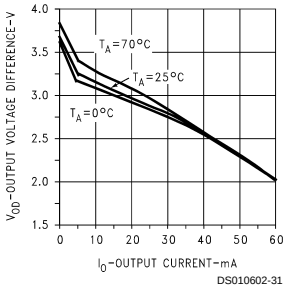
Driver V_{OL} vs I_{OL} vs Temperature



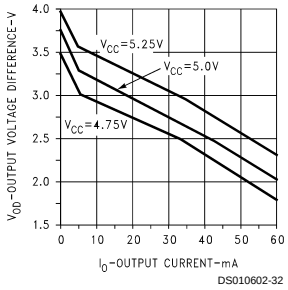
Driver V_{OL} vs I_{OL} vs V_{CC}



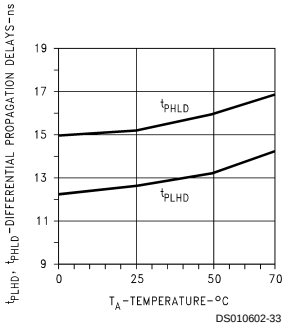
Driver V_{OD} vs I_O vs Temperature



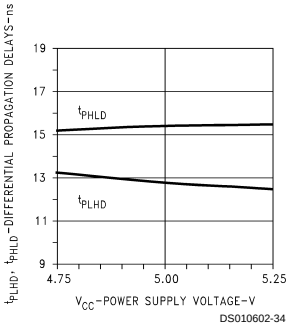
Driver V_{OD} vs I_O vs V_{CC}



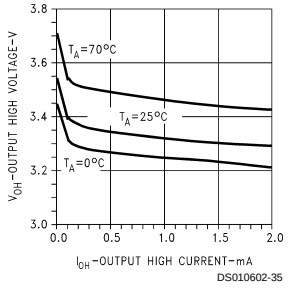
Receiver Differential Propagation Delay vs Temperature



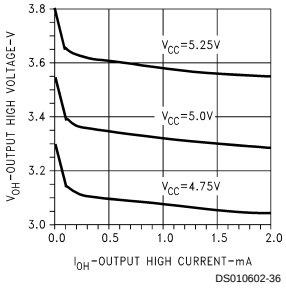
Receiver Differential Propagation Delay vs V_{CC}



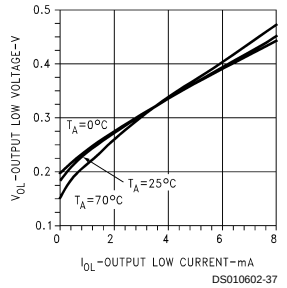
Receiver V_{OH} vs I_{OH} vs Temperature



Receiver V_{OH} vs I_{OH} vs V_{CC}

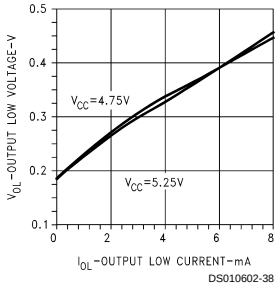


Receiver V_{OL} vs I_{OL} vs Temperature



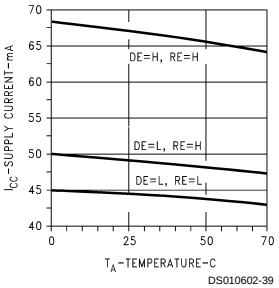
Typical Performance Characteristics (Continued)

Receiver V_{OL} vs I_{OL} vs V_{CC}



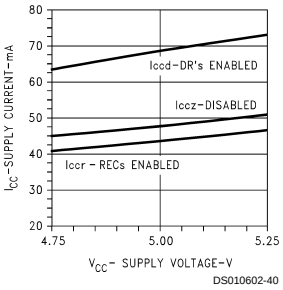
DS010602-38

Supply Current vs Temperature



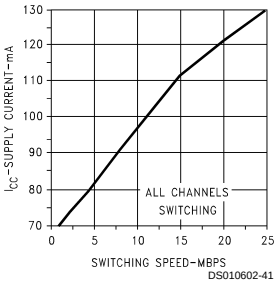
DS010602-39

Power Supply Current vs Power Supply Voltage

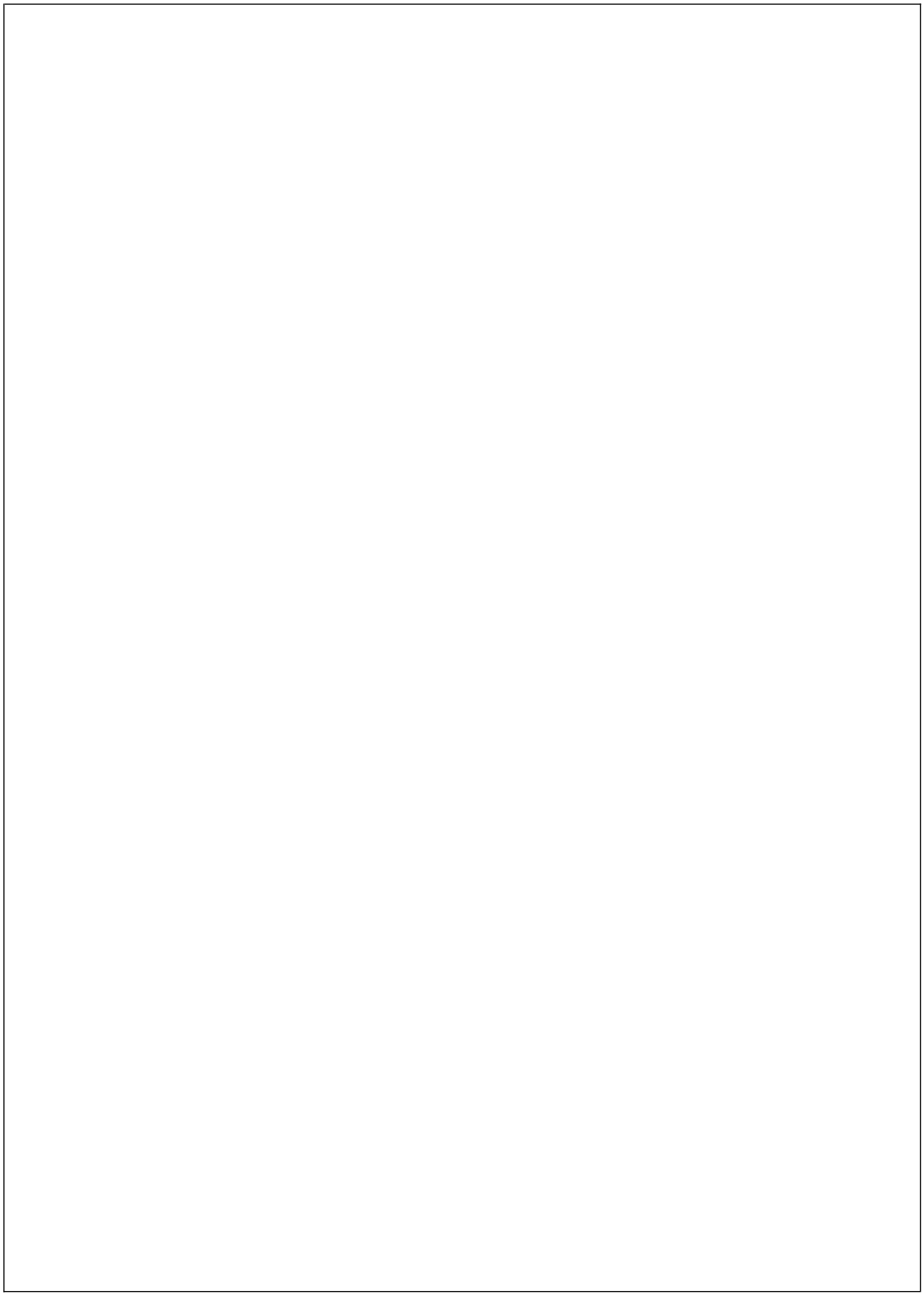


DS010602-40

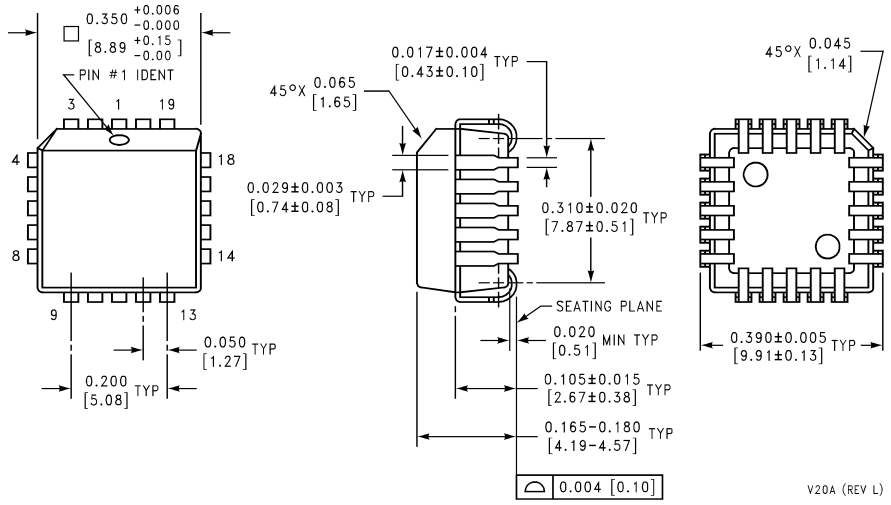
Driver I_{CC} vs Switching Frequency



DS010602-41



Physical Dimensions inches (millimeters) unless otherwise noted



Order Number DS36950
NS Package Number V20A

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

National Semiconductor Corporation
Americas
Tel: 1-800-272-9959
Fax: 1-800-737-7018
Email: support@nsc.com

www.national.com

National Semiconductor Europe
Fax: +49 (0) 1 80-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 1 80-530 85 85
English Tel: +49 (0) 1 80-532 78 32
Français Tel: +49 (0) 1 80-532 93 58
Italiano Tel: +49 (0) 1 80-534 16 80

National Semiconductor Asia Pacific Customer Response Group
Tel: 65-2544466
Fax: 65-2504466
Email: sea.support@nsc.com

National Semiconductor Japan Ltd.
Tel: 81-3-5639-7560
Fax: 81-3-5639-7507